

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	("5327001").PN.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 14:36
L2	1	("6646305").PN.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 14:38
L3	2	(("5162889") or ("5452247")).PN.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 14:49
L4	1	("6177300").PN.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 18:26
L9	1884	(257/532).CCLS.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 18:26
L10	1842	257/532	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 18:26
L11	2696	9 10	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 18:26
L12	1388	11 and (via or hole)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 18:26
L13	529	12 and (circular or round or annular or around or ring)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 18:47
L14	2521	11 and capacit\$	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 18:48
L15	859	12 not 13	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 18:48
L16	802	15 and capacit\$	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 19:07

L17	78	11 and (((upper or top) near2 electrode) near2 (via or hole))	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 19:09
L18	835	capacitor and (semiconductor or substrate) and (((upper or top) near2 electrode) near2 (via or hole))	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 19:13
L19	9636	capacitor with (thin near2 film)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 19:13
L20	1877	19 and via and (circle or round or annular or cylindrical or cylinder or around or ring)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 19:16
L21	492	19 and via and ((circle or round or annular or cylindrical or cylinder or around or ring) with (dielectric or insulat\$))	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 19:23
L22	2367	(capacitor and ring and electrode and via and (dielectric or insulat\$))".clm"	US-PGPUB	OR	OFF	2005/12/01 19:25
L23	1773	(capacitor and (semiconductor or substrate) and ring and electrode and via and (dielectric or insulat\$))".clm"	US-PGPUB	OR	OFF	2005/12/01 19:29
L24	5107	(257/296,532).CCLS.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/12/01 19:29
L25	19	24 and (capacitor and (semiconductor or substrate) and ring and electrode and via and (dielectric or insulat\$))".clm"	US-PGPUB	OR	OFF	2005/12/01 19:29